

High-reliability discrete products and engineering services since 1977

MCR106 SERIES

SILICON CONTROLLED RECTIFIERS

FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

MAXIMUM RATINGS.

Rating	Symbol	Value	Unit
Peak repetitive off-state voltage ⁽¹⁾			
$(T_J = -40 \text{ to } +110^{\circ}\text{C}, \text{ sine wave, } 50 \text{ to } 60\text{Hz, gate open})$			
MCR106-1		30	
MCR106-2		60	
MCR106-3	V_{DRM}	100	V
MCR106-4	V_{RRM}	200	V
MCR106-5		300	
MCR106-6		400	
MCR106-7		500	
MCR106-8		600	
On-state RMS current (180° conduction angles, T _C = 93°C)	I _{T(RMS)}	4.0	А
Average on-state current (180° conduction angles, T _C = 93°C)	I _{T(AV)}	2.55	А
Peak non-repetitive surge current			
(half-cycle, sine wave, 60Hz, T _J = 110°C)	I _{TSM}	25	A
Circuit fusing consideration (t = 8.3ms)	l ² t	2.6	A ² s
Forward peak gate power (pulse width $\leq 1.0 \mu s$, $T_c = 93 \degree C$)	P _{GM}	0.5	W
Forward average gate power (t = 8.3ms, T _C = 93°C)	P _{G(AV)}	0.1	W
Forward peak gate current (pulse width $\leq 1.0 \mu s$, $T_c = 93 ^{\circ}C$)	I _{GM}	0.2	А
Peak reverse gate voltage	V		V
(pulse width $\leq 1.0 \mu s$, $T_c = 93 ^{\circ}C$)	V_{RGM}	6.0	V
Operating junction temperature range	T,	-40 to +110	°C
Storage temperature range	T _{stg}	-40 to +150	°C
Mounting torque ⁽²⁾	-	6.0	In. lb.

Note 1: V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Note 2: Torque rating applies with use of compression washer. Mounting torque in excess of 6 in. lb. does not appreciably lower case-to-sink thermal resistance. Anode lead and heatsink contact pad are common. For soldering purposes, soldering temperatures should not exceed +200°C. For optimum results, an activated flux is recommended.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Maximum	Unit
Thermal resistance, junction to case	R _{eJC}	3.0	°C/W
Thermal resistance, junction to ambient	$R_{\Theta JA}$	75	°C/W
Lead solder temperature (lead length ≥ 1/8" from case, 10s max)	T _L	260	°C

ELECTRICAL CHARACTERISTICS (T_c = 25°C unless otherwise specified)

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Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Peak forward or reverse blocking current	I _{DRM} ,				
$(V_{AK} = Rated V_{DRM} \text{ or } V_{RRM}, R_{GK} = 1000\Omega)$	I _{RRM}				μΑ



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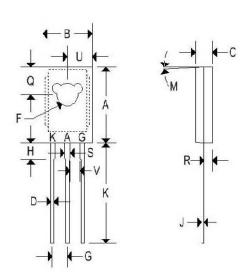
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T _C = 25°C		-	-	10	
$T_C = 110$ °C		-	-	200	
ON CHARACTERISTICS					
Peak forward on-state voltage (3)	V				V
(I _{TM} = 4.0A peak)	V _{TM}	-	-	2.0	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
Gate trigger current (continuous dc) (4)				•	
$(V_{AK} = 7V, R_L = 100\Omega)$					
$(T_C = -40^{\circ}C)$					
Gate trigger voltage (continuous dc) ⁽⁴⁾					
$(V_{AK} = 7V, R_L = 100\Omega)$					
Gate non-trigger voltage ⁽⁴⁾					
$(V_{AK} = 12V, R_L = 100\Omega, T_J = 110^{\circ}C)$					
Holding current					
(V _{AK} = 7V, initiating current = 200mA, gate open)					
DYNAMIC CHARACTERISTICS					
Critical rate of rise of off-state voltage	dv/dt		V/c		
(T _C = 110°C)	αν/αι	-	10	-	V/µs

Note 3: Pulse width≤ 1.0ms, duty cycle ≤ 1%.
Note 4: R_{GK} current is not included in measurement.

MECHANICAL CHARACTERISTICS

Case:	TO-126
Marking:	Body painted, alpha-numeric
Pin out:	See below



		TO	-126		
	Inc	hes	Millin	neters	
	Min	Max	Min	Max	
A	0.425	0.435	10.80	11.050	
В	0.295	0.305	7.490	7.750	
C	0.095	0.105	2.410	2.670	
D	0.020	0.026	0.510	0.660	
F	0.115	0.125	2.920	3.180	
G	0.091	0.097	2.310	2.460	
Н	0.050	0.095	1.270	2.410	
J	0.015	0.025	0.380	0.640	
K	0.595	0.655	15.110	16.640	
М	3°	TYP	3°	IγP	
Q	0.148	0.158	3.760	4.010	
R	0.045	0.055	1.140	1.400	
S	0.025	0.035	0.640	0.890	
U	0.145	0.155	3,680	3.940	
٧	0.040		1.020	-	



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CURRENT DERATING

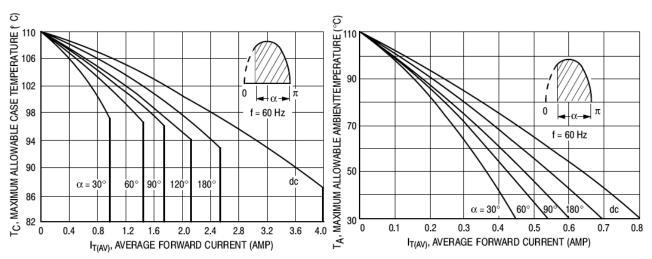


Figure 1. Maximum Case Temperature

Figure 2. Maximum Ambient Temperature